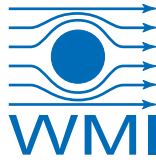




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Circuit quantum electrodynamics with a transmon qubit in a 3D cavity

Master's Thesis
Gustav Andersson

Supervisor: Prof. Dr. Rudolf Gross
Munich, March 2015

Contents

1	Introduction	1
2	Theory	3
2.1	Josephson Junctions	3
2.2	Superconducting qubits	5
2.2.1	The Cooper pair box	6
2.2.2	The transmon qubit	7
2.3	Cavity resonators	10
2.4	Cavity QED and 3D circuit QED	15
2.4.1	Jaynes-Cummings model	16
2.4.2	Dispersively coupled transmon	16
2.4.3	The coupling strength	19
3	Experimental methods and simulations	21
3.1	Aluminium cavities	21
3.1.1	Room temperature setup	23
3.1.2	Cryogenic setup	24
3.2	Qubit spectroscopy	27
3.2.1	3D Transmon	27
3.2.2	Two-tone spectroscopy setup	28
3.3	Simulations	32
3.3.1	Magnetic flux coupling	35
3.3.2	Dual cavity simulation results	36
3.3.3	Bias line filtering	39
4	Experimental results	43
4.1	Cavity characterization	43
4.1.1	Room temperature characterization	43
4.1.2	Frequency tuning	47
4.1.3	Cavities at cryogenic temperatures	50
4.2	Qubit spectroscopy	54
4.2.1	Two-tone continuous wave readout	54
4.2.2	High power spectroscopy	59

4.2.3	ac Stark shift and photon number calibration	63
4.2.4	Dressed cavity transmission spectrum	63
5	Conclusions and outlook	67
A	Dual cavity measurement	71
B	Cavity technical data	73
C	Time domain setup	77
	Bibliography	79
	Acknowledgement	84

List of Figures

2.1	Schematic drawing of an SIS Josephson junction. An insulating oxide barrier separates the two superconducting electrodes.	5
2.2	Bloch sphere schematic. Pure qubit states $ \psi\rangle$ are often represented in spherical coordinates. In this basis we have $ \psi\rangle = e^{i\varphi} \sin\left(\frac{\vartheta}{2}\right) 0\rangle + \cos\left(\frac{\vartheta}{2}\right) 1\rangle$. The polar coordinates are not to be confused with the superconducting phase variables.	6
2.3	Circuit diagram of the Cooper pair box. Charges tunnel onto the island through the Josephson junction, represented by the crossed square. . . .	7
2.4	The transmon qubit equivalent circuit. Compared to the Cooper pair box, an extra capacitance has been added between the island and ground. . .	8
2.5	The first four energy levels of the charge qubit as a function of n_g , plotted for different values of E_J/E_C . The levels are eigenenergies of the Hamiltonian of Eq. (2.7).	9
2.6	Schematic illustration of the 3D transmon design. The pad structures provide the shunt capacitance as well as the resonator coupling. The Josephson junction is marked with the junction energy E_J and junction capacitance E_J . The length of the qubit structure l influences the dipole moment of the structure, which is critical to the electric field coupling. .	10
2.7	Equivalent circuit diagram and 3D schematic design of a tunable transmon. The effective Josephson energy is altered by coupling an external magnetic flux into the split junction loop.	11
2.8	The resonator transmission lineshape is a Lorentzian. The bandwidth of the transmission is determined by the loss rate.	12
2.9	Schematic of a rectangular cavity resonator (top). Electric field distribution of the TE_{101} (bottom left) and TE_{102} (bottom right) modes on the schematic cutplane. The field is polarized perpendicular to the figure plane.	14
2.10	3D cQED schematic	15
2.11	Time evolution of the qubit excited state occupation in the Jaynes-Cummings model for different values of the detuning simulated using QuTiP. The resonant case leads to the entire excitation energy oscillating between qubit and cavity. In the detuned limit, the exchange of energy is blocked almost completely.	17

3.1	CAD generated drawing of the pure aluminium cavity. The alloy cavity has identical internal dimensions, but differs in that the top and bottom metal hull is thicker	22
3.2	Profile drawings showing the internal dimensions of the cavities.	22
3.3	Photographs showing the pure aluminium cavity (left) as well as a pin connector along with samples of the spacers used to adjust the pin insertion depth (right). The numbers on the spacers indicate their height in mm.	22
3.4	The alloy cavity following modifications introducing a magnetically permeable copper face as well as a tuning screw.	23
3.5	The cryogen-free dilution refrigerator used for low-temperature experiments.	25
3.6	Bottom view of the cryostat mixing chamber plate. Both cavities are mounted at the sample stage and connected to the microwave switches.	25
3.7	Circuit diagram of the cryogenic setup used to measure transmission of both the alloy and pure aluminium cavities. The coloured boxes indicate temperature stages of the cryostat.	26
3.8	SEM micrograph of a Josephson junction, as schematically represented in Fig. 2.1.	27
3.9	Microscopy image of the transmon sample. The junction is in the center line between the pads, which are 50 μm apart. The gridded pads have 20 μm by 20 μm cells and the bars are 5 μm wide. During fabrication, the aluminium has not been removed entirely from the grid cells. The blue bar near the bottom is a 100 μm length scale reference.	28
3.10	Alloy cavity with a silicon wafer mounted. At cryogenic temperatures, thermal and mechanical coupling is ensured by adding Indium to the spherical corners of the milled chip frame.	29
3.11	The pure aluminium cavity mounted at the sample stage for qubit spectroscopy. The power splitter in the foreground enables sharing an input line with another experiment.	29
3.12	Circuit diagram of the cryogenic setup used in two-tone spectroscopy. The probe and drive signals are mixed at room temperature using a power combiner. The coloured boxes indicate temperature stages of the cryostat.	31
3.13	CST model of the cavity with a mounted transmon wafer. The dimensions shown in Fig. 3.2. Waveguide ports are added to the model at the top end of the metallic pins, modelled after the Huber and Suhner connectors. The blue colour represents vacuum, brown teflon, grey PEC and the silicon wafer is shown in green.	33

3.14	CST model of flux bias line with $\lambda/4$ filter stubs. The substrate is 26.5 mm long and 3 mm wide and has a thickness of 0.25 mm. The material is modelled after sapphire and has a relative dielectric constant of $\epsilon_r = 11.5$. The stubs vary in length between 5.1 mm and 6.5 mm. The metal structures are 1 μm thick and 10 μm to 15 μm wide.	34
3.15	CST model of the two cavity model, highlighting the qubit and bias line structures. The top right inset shows the port numbering relevant to the S-parameter calculations.	34
3.16	CST simulation of magnetic field penetration from an external coil through a copper face of the cavity. The field value at the transmon chip is relevant to flux bias tuning, and amounts to $B = 4.3 \mu\text{T}$	35
3.17	CST simulation of the electric field distribution from a near-resonant excitation in a two-cavity model (logarithmic scale). The simulated input power is 1 W.	36
3.18	Cross-section of CST simulation of the electric field distribution showing the transmon structure (logarithmic scale). The propagation of the electric field through the flux bias line is clearly suppressed by the $\lambda/4$ stubs. The simulated input power is 1 W.	37
3.19	S-parameter simulation results of intra-cavity (S_{21}) and cross-cavity (S_{41}) transmission with the bridge transmon mounted and pin depth -1.6 mm at all ports.	38
3.20	S-parameter simulation results of intra-cavity (S_{21}) and cross-cavity (S_{41}) transmission with the bridge transmon mounted and pin depth 1.4 mm at all ports.	38
3.21	Time evolution of a qubit coupled resonantly to two cavities. The coupling g , resonator loss and qubit dephasing parameters are derived from the experimental results of Ch. 4. Direct photon exchange between the resonator is assumed to occur at a rate g_{AB} much lower than the qubit-resonator coupling frequency ($g = 10g_{AB}$). The initial state corresponds to a single photon in one of the cavities.	39
3.22	Electric Field distribution from CST simulation of a flux bias line model with $\lambda/4$ filter stubs. The excitation is introduced at the qubit side, where the line is parallel to the short end of the substrate. The simulated excitation frequency is 4.5 GHz, inside the stop-band of the filter stubs.	40
3.23	Simulated transmission $ S_{21} $ between the two endpoints of the bias line, meaning the signal travels through both branches.	41
4.1	Resonant volume defined for simulations in the CST environment (top) and simulated electric field distribution of fundamental cavity mode at 1 W input power (bottom).	44

4.2	Broad frequency sweep of the alloy cavity transmission at room temperature. The peaks corresponding to the first and second cavity modes are marked. The VNA power is set at -10 dBm.	45
4.3	Cavity transmission spectrum data and fit at room temperature compared to simulation. Fitted parameters are shown next to the corresponding peaks. The differences in resonance frequency ($\sim 3\%$) and Q ($\sim 10\%$) are caused mainly by fabrication issues. The different transmission magnitude is attributed to the pin depth calibration.	45
4.4	Quality factor vs. pin insertion depth for simulated and measured configurations.	46
4.5	Alloy cavity transmission with a silicon wafer of the type used as substrate for qubit structure mounted in the center. The first mode is suppressed at room temperatures, where the silicon has a high impurity conductivity. .	47
4.6	Quality factor and resonance frequencies for alloy cavity tuning by pin depth variation. Data points are annotated with the pin depth.	48
4.7	Quality factor and resonance frequencies for alloy cavity tuning by dielectric and shape perturbation. We use the absolute value of the frequency change as the different tuning mechanisms lead to shifts of different sign.	48
4.8	Transmission data (dots) and fit (line) for the alloy cavity at 50 mK before electropolishing. The resonance linewidth (FWHM) equals 15.3 kHz. The measurement is done with a pin depth of -1.1 mm.	51
4.9	Transmission data (dots) and fit (line) for the alloy cavity at 50 mK after electropolishing. The resonance linewidth (FWHM) equals 18.1 kHz. The measurement is done with a pin depth of -1.1 mm.	51
4.10	Calibrated transmission data (dots) and fit (line) for the pure aluminium cavity at 50 mK. The resonance linewidth (FWHM) equals 8.43 kHz. The measurement is done with a pin depth of -1.6 mm.	52
4.11	Loaded quality factor versus estimated input power at the cavity at 50 mK for the aluminium cavity. Single photon power corresponds to an input power of -115 dBm.	53
4.12	Probe tone phase shift data vs. drive frequency. The probe tone power is -42 dBm (average photon number $n_p = 0.5$). at the frequency $f_p = 5.4635$ GHz.	55
4.13	(a) Qubit two-tone spectroscopy. Colourscale indicates phase shift ϕ in degrees of the probe signal, at $f_p = 5.4635$ GHz. The reduced phase shift is observed when the drive tone excites the qubit out of the ground state. Increasing the readout power leads to broadening and ac Stark shift of this transition. The drive tone power is -15 dBm. (b) Qubit transition frequency at different readout powers. The data points are obtained from the best fit (Lorentzian or Gaussian) to two-tone spectroscopy data. . . .	56

4.14	Qubit two-tone spectroscopy in the low power limit. Colourscale indicates phase shift ϕ in degrees of the probe signal, at $f_p = 5.4635$ GHz. The drive tone power is -25 dBm.	57
4.15	Squared qubit linewidth (FWHM) as a function of input power. Linear fit extrapolated to zero power for T_2 estimate.	57
4.16	Qubit two-tone spectroscopy sweeping the drive power. At high drive powers, it is possible to discern the second qubit transition. The probe power amounts to -35 dBm ($n_p = 2.5$).	58
4.17	(a) Two-tone spectroscopy with strong drive. (b) Frequencies for the first and second transition. (c) Anharmonicity $f_{01} - f_{12}$. The drive power is 5 dBm.	58
4.18	(a) Single tone spectroscopy power sweep. At high readout power, the cavity frequency is abruptly downshifted. No qubit drive is applied in this measurement. (b) Two-tone spectroscopy power sweep with -10 dBm drive tone at 3.65 GHz. Due to the ac Stark shift, this drive has a considerable detuning from the first qubit transition. (c) Two-tone spectroscopy power sweep with -10 dBm drive tone at 5.4635 GHz. When driving at the upper branch frequency, the lower branch resonance is observed at all readout powers. (d) Two-tone spectroscopy power sweep with -10 dBm drive tone at 3.58 GHz.	60
4.19	Cavity spectra without qubit drive for different readout powers. At $P_p = -15$ dBm ($n_p = 250$), both branches are observed to coexist.	61
4.20	Cavity model with transmon mounted in the experimental configuration. The image shows the electric field distribution for one half of the cavity, with the cut through the transmon wafer. The simulated input power is 1 W and the pin depth 1.4 mm.	62
4.21	Qubit frequency vs. readout photon population in the cavity. The photon number calibration is obtained by comparing qubit frequency data (red boxes) to the ac Stark shift estimated from the coupling strength calculated from the dispersive shift in Sec. 4.2.2. This estimated ac Stark shift (black dotted line) is plotted for comparison. Fitting a line to the qubit frequency (red line) gives an additional estimate g_{fit} for the coupling strength. The fit is restricted to data below $n_p = 2.5$	64
4.22	Qubit two-tone spectroscopy. Both the drive and readout frequencies are varied in order to observe the effect on the cavity resonance. Colourscale indicates transmission. The resonance frequencies (red line) are obtained by Lorentzian fit, and show a shift when driving at the qubit frequency. .	65
4.23	Dressed cavity frequency as a function of qubit drive frequency and readout power. The cavity frequency minima occur at different drive frequencies due to the ac Stark shift of the qubit. The drive power is -10 dBm. . . .	66

5.1	Rendered image of CAD drawing of the two-cavity concept. The dimensions are those of the simulated 3D model.	69
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Chapter 1

Introduction

Quantum information processing is a rapidly advancing field of physics showing great potential for future applications in the computing industry. The fundamental component of quantum information systems is the quantum bit (qubit), a quantum two-level system whose state can be read and manipulated in a controlled manner. Using arrays of such qubits coupled together, quantum superposition and entanglement of states could enable the implementation of certain algorithms providing an immense increase in efficiency as compared to classical computing. The perhaps most famous example is Shor's algorithm for factorizing integers, with potentially great implications for modern cryptography. On an ideal quantum computer, this algorithm finds the prime factors of any integer in polynomial time [1].

Among the most promising candidates for realizing quantum computing are superconducting qubits. These are electric circuits based on the special physical properties of the Josephson junction, a circuit element with a nonlinear inductance [2]. Named after British physicist Brian Josephson, the Josephson junction consists of two superconducting metal electrodes separated by a thin insulating layer, typically a few nanometres thick. The integration of Josephson junctions into electric circuits has given rise to the field circuit quantum electrodynamics (QED). In this field, circuits play the roles of natural atoms and optical cavities in quantum-optical cavity QED. Thanks to the macroscopic nature of quantum phenomena in superconductivity, qubit properties can to a large extent be engineered to meet desired specifications, rather than just relying on the natural properties of atoms or molecules. Using well developed microwave engineering principles, circuit QED enables study of light-matter interaction by coupling qubits to resonant structures, such as coplanar waveguide resonators.

Due to their size, superconducting qubits are difficult to isolate from their environment. The quantum states necessary for quantum computing or other experimental schemes are sensitive to stray fields and thermal noise. The preservation of the quantum properties of the system, coherence, is therefore an important aspect of qubit design. The transmon qubit [3], conceived in 2007, is designed to mitigate this problem by reducing sensitivity to fluctuations in local electric charge density in the sample. This has helped maintain the strong trend in increasing coherence times for superconducting qubit designs.

In recent developments, the planar circuits where the qubit is embedded have been replaced by three-dimensional cavity resonators. Such configurations offer several advantages, in particular towards coherence. As qubits decay from excited states by emitting a photon, the mode volume of the final photon state may significantly affect this process. These so-called 3D transmons therefore combine the high coupling strength of typical superconducting qubits with long coherence times. This is typically challenging to achieve as strong coupling to the cavity fields usually implies strong coupling also to the environment, inducing loss of coherence. Times for excited state qubit decay, commonly denoted T_1 , close to 100 μs have been recorded [4].

In this thesis, we characterize superconducting cavities for use with transmon qubits. We employ microwave measurement techniques and cryogenics to determine the cavity transmission properties. We proceed to investigate a system with a transmon coupled to a cavity resonator in 3D circuit QED experiments. Using microwave spectroscopy in a dilution refrigerator setup, the qubit parameters and the properties of the combined system are investigated experimentally.

A long-term goal of this project is to extend the qubit-cavity system to a network of two or more resonators, with qubit-mediated interaction. Such a system may allow experimental studies of entangled photon states, where a single photon may be present in different cavities simultaneously. It also shows promise for quantum information processing applications, due to the increased coherence times accessible in cavity resonators. This thesis therefore includes preliminary analysis towards such implementations, mainly from a microwave engineering analysis point of view.

We begin in Ch. 2 by introducing fundamental theoretical concepts regarding superconducting circuits, cavity resonators and light-matter interaction. Having laid the foundation to the investigations carried out in this work, we proceed in Ch. 3 to describe the particulars of the experimental design and setup involved. This section also contains the numerical methods used and the simulation results. The main results obtained are presented in Ch. 4, starting with cavity characterization data. We then outline the results obtained from qubit spectroscopy in single as well as two-tone measurements. Finally, Ch. 5 states our conclusions and provides an outlook.

Chapter 2

Theory

In this section, we introduce the theoretical aspects underlying the experiments carried out and the results presented in this work. The fundamentals of Josephson junctions are discussed, and the relevant energy scales for applications in superconducting circuits are introduced. We outline the principles of superconducting charge qubit circuits and their operation. In particular, the properties and ideas behind the transmon qubit are described.

We also introduce the classical theory of three-dimensional electromagnetic resonators necessary for the investigated implementations. The qubit and resonator theory are then combined to discuss the fundamentals of light-matter interaction in a quantum mechanical picture. These principles are then applied to the parameter range relevant to our experimental configurations.

2.1 Josephson Junctions

A fundamental element in any superconducting qubit design is the Josephson junction, consisting of two superconducting electrodes separated by a thin insulating barrier. In the macroscopic quantum model of superconductivity [5], the density of the superconducting charge carrier component is related to a macroscopic wavefunction of definite magnitude and phase

$$\Psi(\mathbf{r},t) = |\Psi(\mathbf{r},t)| \cdot e^{i\theta(\mathbf{r},t)} = \sqrt{n(\mathbf{r},t)}e^{i\theta(\mathbf{r},t)}. \quad (2.1)$$

The squared magnitude of this wavefunction gives the density $n = n(\mathbf{r},t)$ of the superconducting charge carriers. The presence of a phase θ gives rise to macroscopic quantization and interference phenomena. The origin of this macroscopic state in the formation of electron pairs, called Cooper pairs, of charge $2e$ and spin zero, is explained by the theory of Bardeen, Cooper and Schrieffer (BCS theory) [6].

In a Josephson junction, the separation between two superconducting electrodes is sufficiently small to create a weak coupling between them. The macroscopic superconducting wavefunctions of the electrodes overlap, leading to the tunnelling of Cooper pairs across the barrier. The Josephson junction is so named because of Brian Josephson's prediction

of the Josephson relations for this system, in 1962 [7]. The first Josephson equation reads

$$I_s = I_c \sin(\phi). \quad (2.2)$$

This equation, the current-phase relation, describes the supercurrent flow between the electrodes. The relative phase between the superconductors is given by $\phi = \theta_2 - \theta_1$ and I_c is the critical current, the maximum supercurrent the Josephson current can sustain in a zero voltage state. The second Josephson relation concerns the time evolution of the phase difference when a voltage is applied across the junction,

$$\frac{d\phi}{dt} = \frac{2\pi}{\Phi_0} V. \quad (2.3)$$

This equation is known as the voltage-phase relation. The factor Φ_0 entering on the right-hand side is the magnetic flux quantum, and is equal to $h/2e$. The way both current and voltage are related to the phase causes the Josephson junction to act as a non-linear inductance. In electric circuits, inductances are associated with stored magnetic field energy. The Josephson junction likewise accumulates potential energy, but rather than in a magnetic field it is stored in the kinetic energy of the moving electrons [8]. This *Josephson coupling energy* is given by

$$U = \frac{\Phi_0 I_c}{2\pi} (1 - \cos \phi). \quad (2.4)$$

This energy, whose scale is set by $E_J = \Phi_0 I_c / 2\pi$, will turn out to be important to Josephson junction based qubit schemes. Due to the parallel geometry of the superconducting electrode faces, the Josephson junction also has a capacitance. This gives rise to a capacitive charging energy whenever there is a potential difference across the junction. The relevant scale for this energy is set by $E_C = e^2 / 2C$, where C is the junction capacitance.

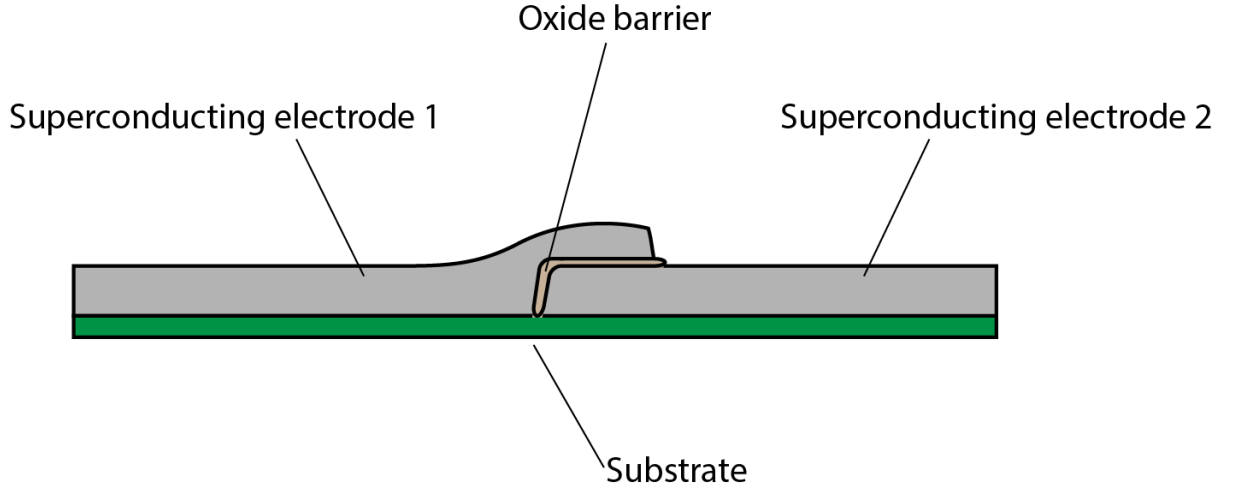


Figure 2.1: Schematic drawing of an SIS Josephson junction. An insulating oxide barrier separates the two superconducting electrodes.

Figure 2.1 shows a schematic drawing of a Josephson junction with a thin oxide tunnel barrier. It is worth noting that although Brian Josephson’s original theoretical predictions were made considering a system as described above with a superconductor-insulator-superconductor (SIS) structure, the Josephson relations also hold for other types of weak links between superconductors. Examples include a barrier of normal state, non superconducting metal as well as a constriction in the form of a bottleneck-like narrow section of the superconductor [9].

2.2 Superconducting qubits

When cooled down to sufficiently low temperatures, where $k_B T \ll E_J, E_C$, Josephson junction circuits exhibit quantum properties. The junction charge and phase variables Q and ϕ then have to be replaced by operators, which crucially obey a quantum commutation relation

$$[\hat{\phi}, \hat{Q}] = 2ie. \quad (2.5)$$

The charge operator \hat{Q} is thus canonically conjugate to the phase, similarly to the position and momentum operators, meaning that they are subject to Heisenberg’s uncertainty principle. This implies that if ϕ is well defined, Q fluctuates strongly and vice versa. This quantum behaviour is the basis for turning superconducting circuits into qubits.

Any quantum two-level system is analogous to a spin $1/2$ system, elegantly described by the Pauli matrices [10]. In this picture, the qubit excited and ground states $|1\rangle$ and $|0\rangle$ are the eigenstates of σ_z . General qubit states in this basis are represented using the Bloch sphere, a unit sphere centered at the origin of a cartesian coordinate system. A point within the enclosed volume corresponds to an expectation value $\mathbf{R} = \langle \vec{\sigma} \rangle$. Qubit operation

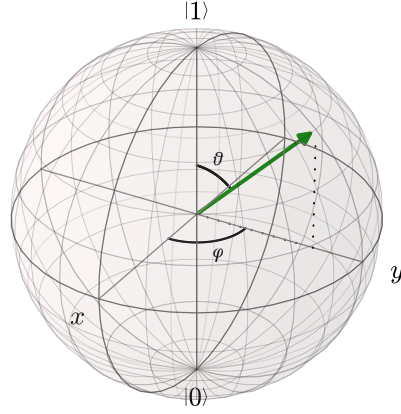


Figure 2.2: Bloch sphere schematic. Pure qubit states $|\psi\rangle$ are often represented in spherical coordinates. In this basis we have $|\psi\rangle = e^{i\varphi} \sin\left(\frac{\vartheta}{2}\right) |0\rangle + \cos\left(\frac{\vartheta}{2}\right) |1\rangle$. The polar coordinates are not to be confused with the superconducting phase variables.

implies manipulation and control of this Bloch vector \mathbf{R} . The norm of the Bloch vector is preserved under unitary time evolution and states on the surface of the Bloch sphere ($|\mathbf{R}| = 1$) are possible observable eigenstates. Such a "pure" state is illustrated in Fig. 2.2. States in the interior $|\mathbf{R}| < 1$ correspond to a statistical mixture, representing a lack of precise knowledge of the quantum state. Such states are probabilistic in a classical sense, not related to quantum uncertainty, and the irreversible time evolution that increases this mixing is one of the major obstacles to successful qubit operation.

The cause of this loss of certainty and the reason we consider it irreversible is that it arises from interaction with the environment, due to the naturally imperfect isolation of the qubit system. Two characteristic timescales are relevant to describe this process. The decay time, $T_1 = 1/\pi\Gamma_1$, is the inverse rate of depopulation of the excited qubit state. The loss of quantum coherence, corresponding to a projection of the Bloch vector onto the z -axis, occurs in the characteristic time $T_2 = 1/\pi\Gamma_2$. As states outside the Bloch sphere are unphysical, depopulation must be accompanied by a certain decoherence, leading to the limit $\Gamma_2 \geq \Gamma_1/2$.

2.2.1 The Cooper pair box

The single Cooper pair box (CPB) couples a small superconducting island via a Josephson junction to a gate electrode. Figure 2.3 shows an equivalent circuit diagram. Two characteristic energies are of interest for this system. The capacitive coupling of the island to the environment produces a charging energy when a gate voltage is applied or the island carries excess charge. This island is sufficiently small to make a single Cooper pair the relevant charge scale (hence its name), leading us to introduce the dimensionless charge variable $n = Q/2e$ and modify the charging energy scale $E_C = e^2/2C_\Sigma$ to account

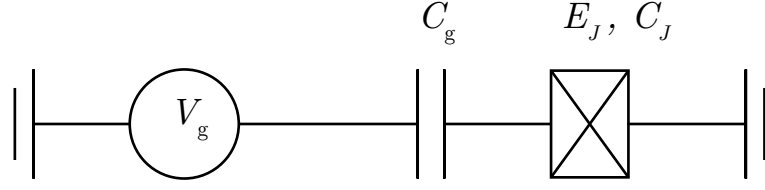


Figure 2.3: Circuit diagram of the Cooper pair box. Charges tunnel onto the island through the Josephson junction, represented by the crossed square.

for the additional capacitance. The total capacitance $C_\Sigma = C_g + C_J$ is the sum of the gate and Josephson junction capacitances. Together with the Josephson energy of Eq. (2.4), we obtain a circuit Hamiltonian

$$\hat{H} = 4E_C (\hat{n} - n_g)^2 - E_J \cos \hat{\phi}. \quad (2.6)$$

The effective offset charge introduced by the gate bias V_g is $n_g = C_\Sigma V_g / 2e$. Using the quantum commutation relation $[\hat{n}, \hat{\phi}] = i$, it is possible to express this Hamiltonian in the charge basis as [11]

$$\hat{H} = 4E_C (\hat{n} - n_g)^2 - \frac{E_J}{2} \sum_n |n+1\rangle \langle n| + |n+1\rangle \langle n| \quad (2.7)$$

For qubit operations, the CPB is typically biased at the "sweet spot" $n_g = 1/2$, where the charging energy degeneracy of the $n = 0$ and $n = 1$ states is only broken by the Josephson energy. There are two distinct advantages with this regime. As the charging energy is typically dominant, $E_C \gg E_J$, the higher charge energy levels will be far away, so that a two-level approximation will be valid for the system in this case. In addition, this bias point provides reduced sensitivity to charge noise fluctuations, an important cause of decoherence.

2.2.2 The transmon qubit

The transmon is a qubit design similar to the Cooper pair box. It differs in that a shunt capacitance is added between the gate and the island (cf. Fig. 2.4). By increasing the capacitance of the island, this lowers the charging energy $E_C = e^2/2C$, leading to an increased E_J/E_C ratio. A higher E_J/E_C leads to a more harmonic energy spectrum, and also flattens the charge dispersion. By charge dispersion we mean the relationship between the qubit eigenenergies and offset charge n_g . A steep charge dispersion implies the energies change rapidly with n_g , and vice versa. While a certain anharmonicity is required for the two-level approximation of the qubit to remain valid, a flattened charge dispersion can significantly mitigate the problem of charge noise dephasing. A critical property to the operation of the transmon is the fact that as E_J/E_C is increased, the charge dispersion is exponentially suppressed, the anharmonicity only reduces by a power law. The result is

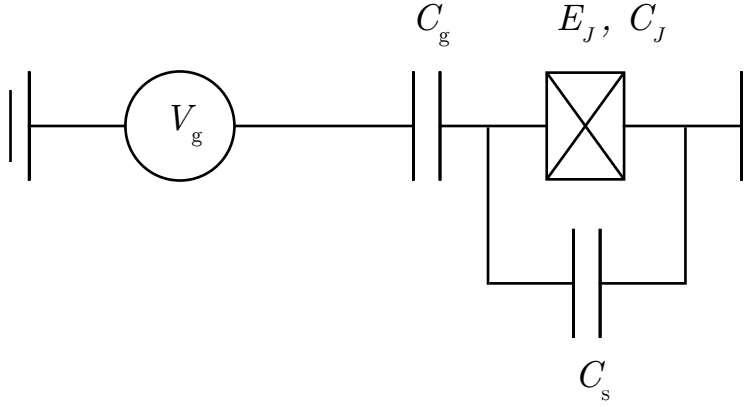


Figure 2.4: The transmon qubit equivalent circuit. Compared to the Cooper pair box, an extra capacitance has been added between the island and ground.

that the n_g -dependence of the energy levels may be practically eliminated, while retaining sufficient anharmonicity for qubit operation. The eigenenergies of the four lowest qubit levels are plotted for different values of E_J/E_C in Fig. 2.5. The energy eigenvalues were obtained using the QuTiP library [12].

Applying second order perturbation theory to find the transmon energies gives for the first two transitions gives [3]

$$E_{01} = \sqrt{8E_CE_J} - E_C \quad (2.8)$$

$$E_{12} = \sqrt{8E_CE_J} - 2E_C \quad (2.9)$$

where E_{01} and E_{12} are the energies of the first and second transitions, respectively. They are related to the corresponding transition frequencies f_{ij} by Planck's constant, $E_{ij} = hf_{ij}$. Transmon qubits are typically designed to operate in the $E_J/E_C \sim 50$ regime. We then get an approximate relative anharmonicity

$$A_{rel} \equiv \frac{E_{01} - E_{12}}{E_{01}} = \sqrt{\frac{E_C}{8E_J}}. \quad (2.10)$$

Though commonly referred to as charge qubits, this term is not entirely consistent with the fact that the Josephson energy dominates over the charging energy in most applications. The flattened charge dispersion of the transmon has an important implication for qubit experiments besides the improved coherence lifetime. Since n_g is not a relevant tuning parameter any more, no bias circuitry is necessary to ensure functional operation. This makes the transmon suitable for applications where control circuits may be impractical to implement. Relevant for this thesis is the three-dimensional configuration enclosing the transmon in a superconducting cavity. Here, we let the shunt capacitance serve also as the antennas necessary for the interaction with the electric field. As seen in the schematic

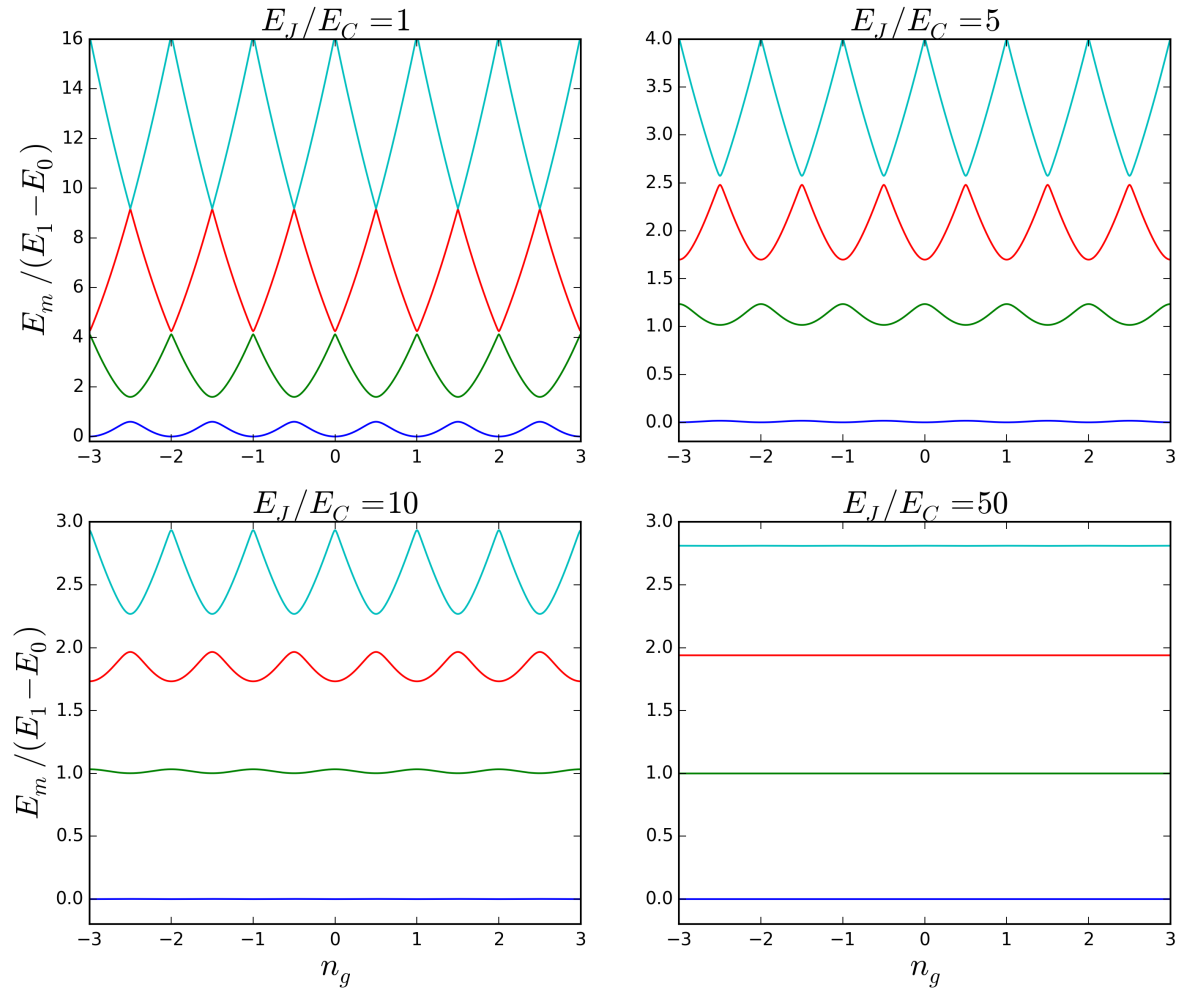


Figure 2.5: The first four energy levels of the charge qubit as a function of n_g , plotted for different values of E_J/E_C . The levels are eigenenergies of the Hamiltonian of Eq. (2.7).

presented in Fig. 2.6, this leads to a design less complex than the equivalent circuit diagram may suggest.

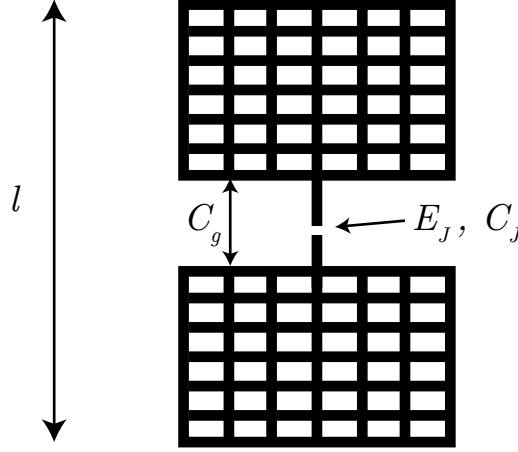


Figure 2.6: Schematic illustration of the 3D transmon design. The pad structures provide the shunt capacitance as well as the resonator coupling. The Josephson junction is marked with the junction energy E_J and junction capacitance E_J . The length of the qubit structure l influences the dipole moment of the structure, which is critical to the electric field coupling.

While the low charging energy of the transmon removes the relevance of a gate bias voltage, a modification enabling tuning of the Josephson energy may substantially expand the scope of possible experiments [13]. This is done by splitting the junction into two symmetric branches, effectively turning it into a loop with two Josephson junctions, commonly known as a superconducting quantum interference device (SQUID) [8]. Flux quantization requires the total flux penetrating the loop be an integer multiple of Φ_0 [8]. An important consequence is an effective change in E_J when an external flux is applied, as screening currents in the loop arise to compensate the bias flux and maintain flux quantization.

The circuit diagram of a tunable transmon is displayed in Fig. 2.7. The split junction has an effective combined capacitance and flux tunable Josephson energy.

2.3 Cavity resonators

A 3D cavity resonator is a vacuum volume enclosed in metal. The eigenmodes of the electromagnetic field in such structures have a dilute field strength and large vacuum participation with a minimum of lossy components inside the mode volume. As a result it is relatively easy to operate such cavities at a low photon loss rate. The damping of the resonator is described by the dimensionless quality factor, or Q-factor, defined as ratio of energy stored in the electromagnetic field to the loss per period of oscillation T , multiplied by a factor of 2π

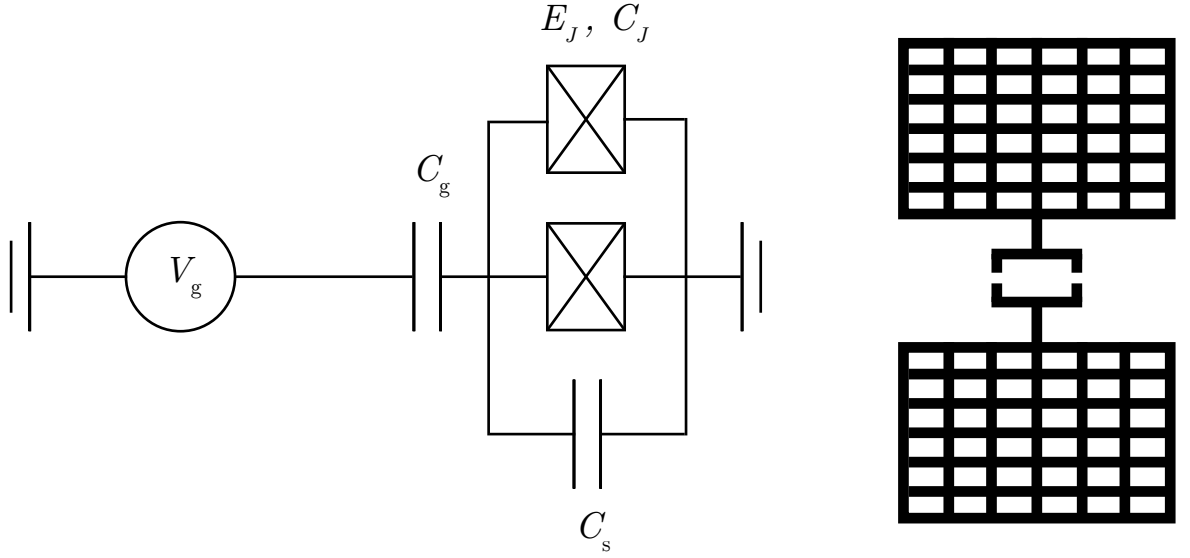


Figure 2.7: Equivalent circuit diagram and 3D schematic design of a tunable transmon. The effective Josephson energy is altered by coupling an external magnetic flux into the split junction loop.

$$Q = \frac{2\pi}{T} \frac{U}{P_d} = \frac{\omega U}{P_d}. \quad (2.11)$$

The stored energy is given by U . The power dissipation due to resonator losses is described by P_d and ω is the angular frequency of the oscillations. In the limit where $Q \gg 1$, the cavity transmission has a Lorentzian lineshape centered at the resonance frequency, with a linewidth determined by the loss rate κ . The Q-factor may then be expressed as

$$Q = \frac{\omega_r}{\kappa} = \frac{\omega_r}{\Delta\omega_r}. \quad (2.12)$$

The resonant bandwidth $\Delta\omega_r = \kappa$ is given by the full width at half maximum (FWHM) of the Lorentzian. This is illustrated in Fig. 2.8. The quality factor may be decomposed into the internal and external quality factors. The internal Q-factor Q_{int} describes internal losses in the metal surface or absorption from two-level systems inside the resonant volume. The external Q-factor Q_{ext} accounts for photons exiting the cavity through the input or output lines that couple the cavity to the environment, in this case the setup electronics. Equation (2.12) gives the total, or loaded quality factor. As the loss rates through different channels add up, and the Q-factor is reciprocal to loss, the total quality may be calculated as

$$\frac{1}{Q} = \frac{1}{Q_{\text{ext}}} + \frac{1}{Q_{\text{int}}}. \quad (2.13)$$

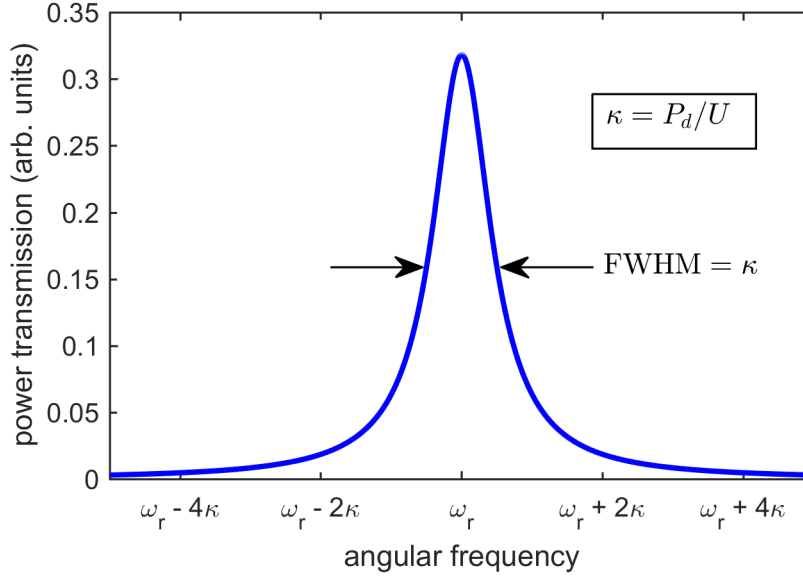


Figure 2.8: The resonator transmission lineshape is a Lorentzian. The bandwidth of the transmission is determined by the loss rate.

Internal loss

The cavity losses that yield the internal quality factor occur mainly in the conducting metal walls, and so depend on the surface resistivity of the material. The power dissipation in the walls is given by [14]

$$P_{\text{walls}} = \frac{R_s}{2} \int_{\text{walls}} |H_t|^2 ds. \quad (2.14)$$

The surface resistivity is denoted by R_s and H_t is the magnetic field tangential to the cavity surface. A common approach to achieve high Q-factors is the use of superconducting cavities, which have minimal surface resistivity. Much of the development towards low-loss resonators and other superconducting radio frequency applications has been done within accelerator physics, aiming at methods to efficiently accelerate charged particles. An expression for the surface resistivity can be formulated using BCS theory [15]

$$R_s = R_{\text{BCS}} + R_{\text{res}} \quad (2.15)$$

where R_{BCS} is the BCS surface resistivity, up to a prefactor given by

$$R_{\text{BCS}} \propto \frac{\omega^2}{T} e^{-1.76T_c/T}. \quad (2.16)$$

Dissipation occurs due to oscillations in normal-component electrons induced by the penetration of the magnetic field into the metal. The density of electrons not bound in

Cooper pairs decreases exponentially with T_c/T , where T_c is the superconducting critical temperature. The other term in the total surface resistivity is the residual resistivity R_{res} . It is associated with surface imperfections, such as lattice distortions and defects, as well as trapped magnetic flux. The surface resistivity is independent of temperature, but surface treatment approaches such as electropolishing have been shown to reduce this component [16]. Apart from losses to the cavity walls, internal losses may arise from absorption due to two-level systems in dielectrics present within the mode volume, such as the qubit chip substrate.

Cavity modes

We seek to fit a transmon qubit inside an approximately rectangular cavity. The lowest electromagnetic field modes of such a cavity and the ones relevant for our qubit experiments are the TE_{10l} modes, $l = 1, 2$. In this context, TE stands for transverse electric, meaning the electric field is everywhere perpendicular to the direction of propagation. Letting the polarization define the y -axis gives $\mathbf{E} = E_y \mathbf{e}_y$. In a rectangular cavity resonator, the electric field of the TE_{10l} modes is then given by [14]

$$E_y = E_0 \sin\left(\frac{\pi x}{a}\right) \sin\left(\frac{l\pi z}{d}\right). \quad (2.17)$$

The first two modes are visualized in Fig. 2.9. The fundamental mode has an electric field anti-node in the cavity center and the length of the cavity corresponds to $\lambda/2$, meaning there is one standing wave antinode in the propagation direction. The second cavity mode has two standing wave antinodes along the length of the cavity d , does however not correspond to twice the frequency of the first mode.

Scattering parameters

The transmission and reflection amplitudes of signals coupled into the cavity are often described using scattering parameters, or S-parameters. Generally, S-parameters describe the propagation of electrical signals between ports in a network and are represented as a matrix [14]:

$$\begin{bmatrix} V_1^- \\ V_2^- \\ \vdots \\ V_n^- \end{bmatrix} = \begin{bmatrix} S_{11} & S_{12} & \cdots & S_{1n} \\ S_{21} & S_{22} & \cdots & S_{2n} \\ \vdots & \vdots & \ddots & \vdots \\ S_{N1} & S_{N2} & \cdots & S_{NN} \end{bmatrix} \begin{bmatrix} V_1^+ \\ V_2^+ \\ \vdots \\ V_n^+ \end{bmatrix} \quad (2.18)$$

The incident voltage signal at port i is given by V_i^+ and V_i^- represents the outgoing amplitude at the same port. The individual matrix elements S_{ij} may be determined by exciting port j while terminating all others except port i with no impedance mismatch.

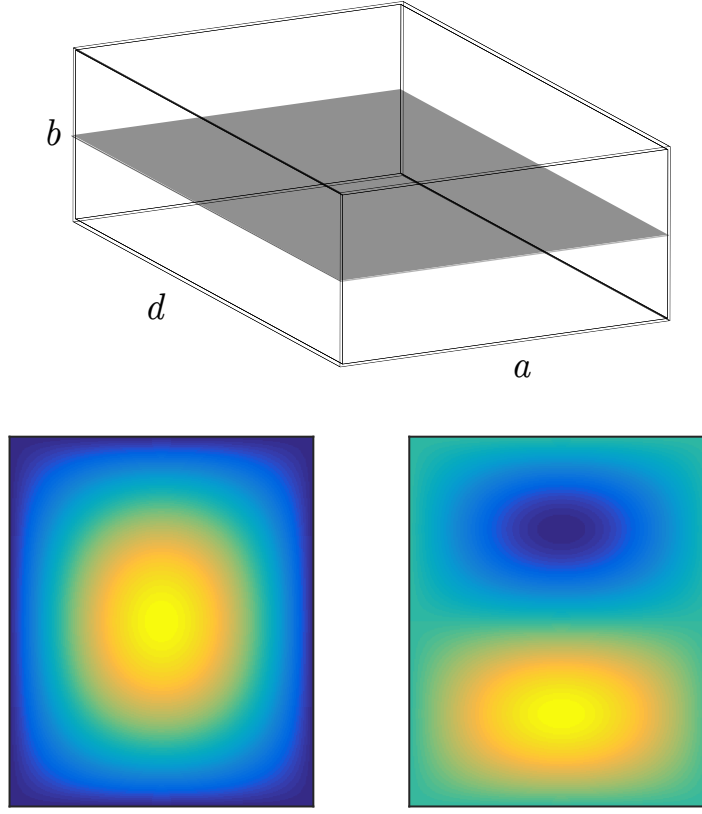


Figure 2.9: Schematic of a rectangular cavity resonator (top). Electric field distribution of the TE_{101} (bottom left) and TE_{102} (bottom right) modes on the schematic cutplane. The field is polarized perpendicular to the figure plane.

We may express this as

$$S_{ij} = \left. \frac{V_i^-}{V_j^+} \right|_{V_k^+ = 0, k \neq j}. \quad (2.19)$$

A network without active components, such as circulators or amplifiers, has a symmetric scattering matrix. Furthermore, if the S-matrix is non-unitary, this indicates internal losses are present in the network.

Cavities with one input and one output port may be regarded as a two-port network in scattering matrix analysis. From the S-parameters we can determine the quality factor and its internal and external components. The ratio of incident to transmitted power is given by $|S_{21}|^2$. Therefore $|S_{21}(\omega)|^2$ will describe a Lorentzian lineshape as plotted in Fig. 2.8, providing the resonator quality. The external and internal loss components may be determined by accounting for the amplitude reflected back at the input. For a two-port network they are related by [17]

$$Q_{\text{int}} = (1 + k_1 + k_2)Q. \quad (2.20)$$

The coupling coefficients k_i quantify the how strongly port i is coupled to the system environment. They are given by the scattering parameters at the resonance frequency f_r :

$$k_i = \frac{|S_{21}(f_r)|^2}{1 - |S_{ii}(f_r)|^2 - |S_{21}(f_r)|^2}. \quad (2.21)$$

Measuring the magnitudes of the reflected and transmitted signals of a two-port cavity will thus enable characterization in terms of internal and external quality, as well as the coupling coefficients. Assuming the cavity is connected to the environment in a symmetric fashion ($k_1 = k_2$), it is sufficient to record the scattering amplitudes $|S_{21}|$ and $|S_{11}|$.

2.4 Cavity QED and 3D circuit QED

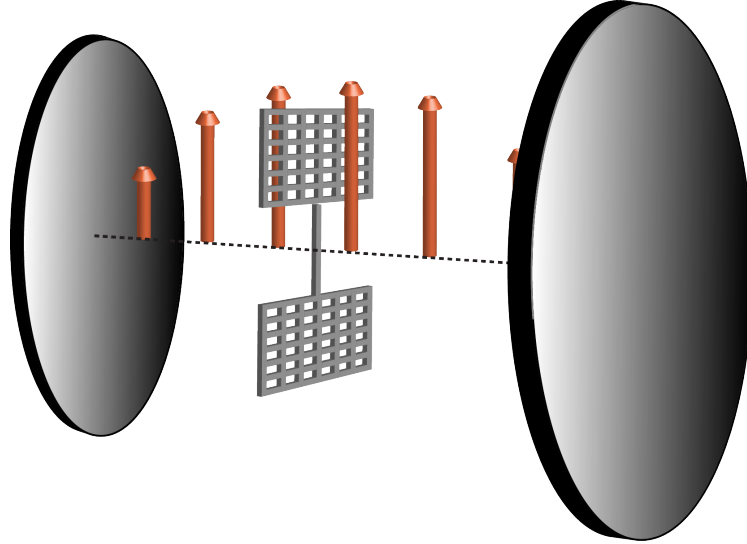


Figure 2.10: 3D cQED schematic

We are now ready to examine the combined system of qubit and resonator. The theory describing the interaction between a two-level system and a quantized electromagnetic field was first developed in the context of cavity quantum electrodynamics (cavity QED) [18]. Rather than artificial qubits, cavity QED involves atoms coupled to light fields in optical cavities, a research field that notably lead to the 2012 Noble Prize in physics being awarded to Serge Haroche and David Wineland [19]. Starting out with a discussion of the fundamental model of this interaction, the Jaynes-Cummings model, we then apply this formalism to the transmon. Finally, we describe in greater detail the physics behind the coupling of the transmon to the microwave field. Figure 2.10 shows a schematic drawing of the interaction involved in this 3D circuit QED picture, with a transmon qubit polarized by an electric field confined between two mirrors.

2.4.1 Jaynes-Cummings model

The quantum mechanical interaction between a two-level atom and a single resonant cavity mode gives rise to the well known Jaynes-Cummings Hamiltonian. As two-level systems are generally described using Pauli matrices, the atomic state enters the Hamiltonian as $\hat{H}_a = (\hbar\omega_a/2) \hat{\sigma}_z$. The resonator mode is described by a quantum harmonic oscillator and appears as $\hat{H}_r = \hbar \left(\hat{a}^\dagger \hat{a} + 1/2 \right)$. The non-trivial dynamics of the system arise due to a third term in the Hamiltonian, accounting for the coupling of the atomic dipole moment of the atom and the cavity electric field. The electric field operator corresponds to the position operator of the harmonic oscillator. Ignoring quickly oscillating terms, this gives $\hat{H}_{\text{int}} = \hbar g \left(\hat{a} \hat{\sigma}^+ + \hat{a}^\dagger \hat{\sigma}^- \right)$, where $\hat{\sigma}^+$ ($\hat{\sigma}^-$) is the raising (lowering) operator for the atomic state. The strength of the interaction is given by the parameter g , the coupling strength, which provides a characteristic angular frequency for the exchange of energy between atom and cavity. We will find reason to return to this important quantity below. For $g \ll \omega_q, \omega_r$ and ignoring any losses or decoherence, we obtain

$$\hat{H} = \frac{\hbar\omega_a}{2} \hat{\sigma}_z + \hbar\omega_r \left(\hat{a}^\dagger \hat{a} + \frac{1}{2} \right) + \hbar g \left(\hat{a} \hat{\sigma}^+ + \hat{a}^\dagger \hat{\sigma}^- \right). \quad (2.22)$$

In 3D circuit QED, a qubit placed inside a cavity resonator is substituted for the atom, but the dynamics of the system still obey Eq. (2.22). For the transmon qubit however, the low anharmonicity may require taking higher qubit levels into account in certain parameter ranges.

For the Jaynes-Cummings Hamiltonian to describe well the time evolution of a 3D circuit QED system, it is necessary to reach the strong coupling limit, where the coupling strength is larger than the qubit decay and cavity loss rates ($g > \kappa, \Gamma_1, \Gamma_2$). Otherwise, the non-Hermitian interaction with the environment will dominate the system dynamics.

2.4.2 Dispersively coupled transmon

The time evolution generated by Eq. (2.22) differs considerably depending on whether the qubit frequency is near the cavity resonance. If the magnitude of the detuning $\Delta \equiv \omega_q - \omega_r$ is smaller than the coupling strength, the first excited state of the system will see energy being coherently transferred back and forth between qubit and resonator. Thus, neither a ground state qubit with a single cavity photon, nor an excited state qubit in an empty cavity are eigenstates of the system. The system investigated below (cf. Sec. 4.2) couples the cavity to a qubit whose first transition frequency is far detuned from the fundamental mode. This parameter range, where $\Delta \gg g$, is known as the dispersive regime. The large detuning inhibits the exchange of energy between qubit and resonator, resulting in eigenstates close to their bare parameters. Figure 2.11 shows how the state of an initially excited qubit evolves depending on the detuning in an ideal picture without decay or resonator losses. For an open system, with losses and decoherence induced by

the environment, the time evolution of mixed states is described using density matrix formalism [20], incorporating Lindblad operators for the decay [21]. For a review of the dynamics of such systems, see Ref [22].

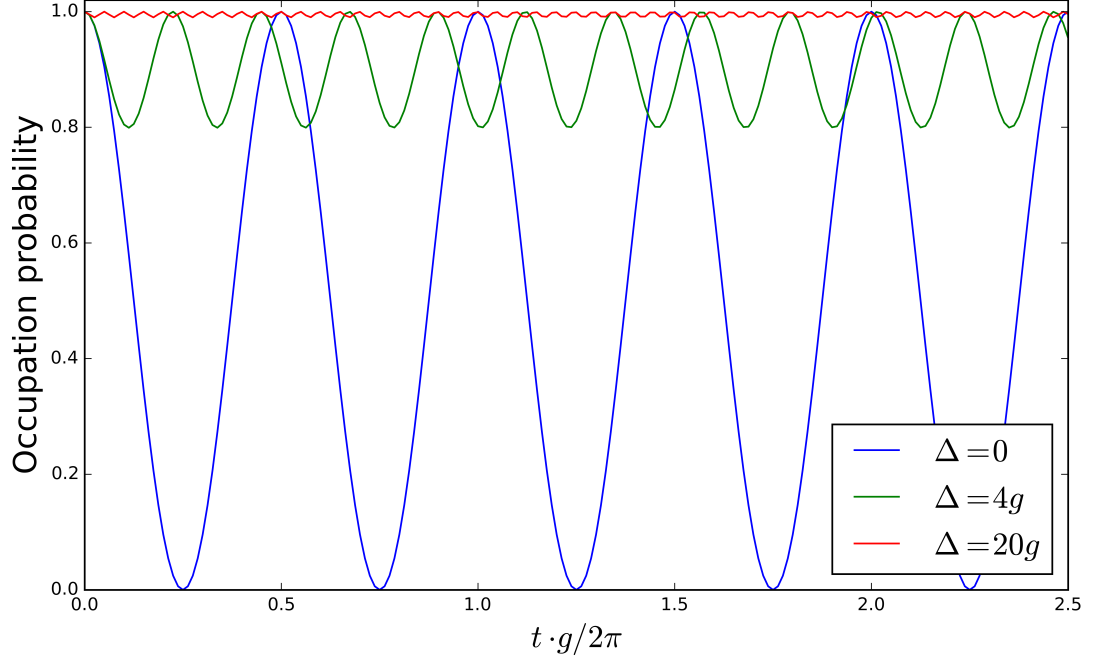


Figure 2.11: Time evolution of the qubit excited state occupation in the Jaynes-Cummings model for different values of the detuning simulated using QuTiP. The resonant case leads to the entire excitation energy oscillating between qubit and cavity. In the detuned limit, the exchange of energy is blocked almost completely.

In the dispersive limit, a unitary transformation may be applied to eliminate the coupling. The deviations from the bare, uncoupled qubit and resonator parameters can then be obtained from perturbation theory. In the two-level approximation this yields an effective Hamiltonian [23]

$$\hat{H}_{\text{eff}} = \hbar \left(\omega_r + \frac{g^2}{\Delta} \hat{\sigma}_z \right) \hat{a}^\dagger \hat{a} + \frac{\hbar}{2} \left(\omega_q + \frac{g^2}{\Delta} \right) \hat{\sigma}_z. \quad (2.23)$$

We note how the cavity field deviates from the bare resonator by the qubit state dependent shift of $\pm g^2/\Delta$. Known as the dispersive shift, this allows readout of the qubit state via the cavity. Grouping together terms in Eq. (2.23) acting on the qubit state, we obtain the qubit frequency in the composite system as

$$\omega_{01} = \omega_q + 2 \frac{g^2}{\Delta} \left(\hat{a}^\dagger \hat{a} + \frac{1}{2} \right). \quad (2.24)$$

Qubit and resonator states and frequencies in the combined system are often referred to as the *dressed* state frequencies. This is a way to distinguish the composite eigenstates from the parameters of the isolated qubit and cavity.

For the transmon in the dispersive regime, the moderate anharmonicity may lead to higher qubit transitions affecting the dispersive shift of the cavity. In second order perturbation theory, the second transmon level also appears in the Hamiltonian. The result is a reduced dispersive shift and the effective Hamiltonian

$$\hat{H}_{\text{eff}} = \hbar \left(\omega_r - \frac{\chi_{12}}{2} + \chi \hat{\sigma}_z \right) \hat{a}^\dagger \hat{a} + \frac{\hbar}{2} (\omega_q + \chi_{01}) \hat{\sigma}_z. \quad (2.25)$$

We introduced here the interaction parameters

$$\chi = \chi_{01} - \chi_{12}/2 \quad (2.26)$$

$$\chi_{ij} = \frac{g^2}{\Delta_i} \quad (2.27)$$

where $\Delta_i \equiv \omega_{i-1,1} - \omega_r$ is the detuning between the i th transition and the resonator. Combining these expressions, the coupling strength can be determined from a recorded dispersive shift as

$$g = \left(\frac{\chi}{\frac{1}{\Delta_1} - \frac{1}{2\Delta_2}} \right)^{1/2}. \quad (2.28)$$

This relation allows for measurement of g via the cavity in a photon number independent way. It is therefore highly useful for determining the coupling strength and calibrating the photon number population of the cavity.

Since, as illustrated in Fig. 2.11, the qubit-resonator detuning prevents the qubit from decay by emitting a photon into the cavity mode, it is reasonable to expect an effect on the characteristic decay time T_1 . By Fermi's golden rule, the rate of spontaneous emission of an excited state, the vacuum rate of photon emission decay, is given by [24]

$$\Gamma = 2\pi g(\omega)^2 D(\omega). \quad (2.29)$$

This rate depends on the final photon density of states D . Whereas in free space, the volume normalized density of states writes

$$D(\omega) = \frac{\omega^2}{\pi^2 c^3}, \quad (2.30)$$

the cavity Lorentzian filtering leads to an approximate expression for high Q resonators

$$D(\omega) = \frac{1}{\pi} \frac{\kappa/2}{(\omega - \omega_r)^2 + (\kappa/2)^2}. \quad (2.31)$$

This leads to a strong modulation of the decay rate due to the cavity impact on the photon density of states. For a qubit resonant with the cavity, the decay rate equals g in the strong coupling limit, much larger than the free space decay rate Γ_{free} . For qubits or atoms resonantly coupled to a cavity, the parameter g determines the rate of exchange of energy between them. This is one of the reasons why resonators are important to the study of light-matter interaction.

In the far detuned limit the decay rate is instead suppressed by the Lorentzian filtering of the cavity. Compared to the free space value, it is reduced by a factor depending on Q as well as a geometry factor.

$$\Gamma = \Gamma_{free} \frac{3}{16\pi^2 Q} \frac{\lambda^3}{V} \quad (2.32)$$

This coefficient is known as the Purcell factor and the associated effect is called the Purcell effect, after their discoverer E.M. Purcell [25]. A consequence of the Purcell effect is that high quality resonators can be used to increase coherence times. This entails a compromise with respect to measurement, as a high total Q requires the coupling of the cavity to the measurement setup to be weak. High internal quality is however always preferable. Since reaching high Q_{int} is typically easier with 3D cavities than planar structures, the longest qubit coherence times have been recorded in such configurations.

It is clear that the system dynamics differ substantially depending on the cavity-qubit detuning. With a split junction transmon as outlined in Fig. 2.7 and a some means of applying external magnetic flux through the loop, it is possible to tune the experiment continuously and in situ between the dispersive and resonant limits.

2.4.3 The coupling strength

In the Jaynes-Cummings model, the electric field couples to the dipole moment of the atom. The characteristic coupling strength per photon g is given by

$$g = \frac{\mu E_{rms}}{\hbar} \quad (2.33)$$

where μ is the expectation value of the dipole moment operator $-e\mathbf{r}$ applied to the atomic state and E_{rms} the root mean square of the vacuum electric field.

For the 3D transmon, μ is given by the dipole moment of the qubit structure where the Cooper pair charge $2e$ has been displaced from one pad to the other [26]. This dipole moment couples to the y-component of the vacuum RMS electric field of the first cavity mode at the qubit position. With electromagnetic FEM computations, we are able to compute these quantities and provide an a priori estimate for the coupling strength.

The vacuum electric field fluctuations for a single mode is given by [27]

$$E_{rms} = \sqrt{\frac{\hbar\omega}{2\epsilon_0 V}}. \quad (2.34)$$

Taking V to be the cavity volume would imply the assumption that the field is evenly distributed inside the cavity. A more rigorous consideration takes into account the field distribution of the fundamental cavity mode and relates it to the field at the qubit position. Instead of the cavity volume, we calculate the *mode volume* of the first resonant cavity mode, which we define as

$$V_{\text{mode}} = \frac{\int_V \epsilon(\mathbf{r}) \mathbf{E}^2(\mathbf{r}) d^3r}{\epsilon(\mathbf{r}_q) \mathbf{E}^2(\mathbf{r}_q)}. \quad (2.35)$$

Here, \mathbf{r}_q refers to the qubit position inside the cavity. As the transmon is small compared to the fundamental mode wavelength, its dimensions may be disregarded for this analysis. For a rectangular cavity with homogeneous dielectric constant and side lengths a, b and d , integrating the analytical expression for the TE_{101} mode gives $V_{\text{mode}}/(abd) = 1/4$. An approach to refine this figure would be to use a numerical simulation more accurately representing the experimental design. Obtaining the electrodynamic parameters μ and V_{mode} in this manner, we may obtain an estimate of the coupling strength from

$$g = \mu \sqrt{\frac{\omega}{2\hbar\epsilon_0 V_{\text{mode}}}}. \quad (2.36)$$

In cavity QED with atoms, coupling strengths rarely exceed $g/2\pi = 20$ MHz. As it has a much larger dipole moment, the transmon couples much more strongly to the electric field. For transmons coupled to 3D cavities, couplings $g/2\pi > 100$ MHz have been observed. With typical decay rates $\Gamma_1/2\pi$ on the order of 1 MHz, 3D transmon configurations are usually not difficult to operate in the strong coupling regime.